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Realization of a Metallic State in $1T$ -TaS₂ with Persisting Long-Range Order of a Charge Density Wave

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Metallization of $1T$ -TaS₂ is generally initiated at the domain boundary of a charge density wave (CDW), at the expense of its long-range order. However, we demonstrate in this study that the metallization of $1T$ -TaS₂ can be also realized without breaking the long-range CDW order upon surface alkali doping. By using scanning tunneling microscopy, we find the long-range CDW order is always persisting, and the metallization is instead associated with additional in-gap excitations. Interestingly, the in-gap excitation is near the top of the lower Hubbard band, in contrast to a conventional electron-doped Mott insulator where it is beneath the upper Hubbard band. In combination with the numerical calculations, we suggest that the appearance of the in-gap excitations near the lower Hubbard band is mainly due to the effectively reduced on-site Coulomb energy by the adsorbed alkali ions.

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$1T$ -TaS₂ has been extensively studied for decades as a unique transition metal dichalcogenide compound hosting the ground state of a Mott insulator [1–3] intertwined with a commensurate charge density wave (CDW) [4]. A series of temperature dependent CDW orders have been discovered [2,5,6], and a large electron-phonon coupling has been demonstrated in $1T$ -TaS₂ which may be associated with the formation of the CDW state [7,8]. Realization of superconductivity in $1T$ -TaS₂, particularly by doping [9,10] or applying pressure [11], further makes it an alternate model system to study the interplay between superconductivity and strong correlation physics [12]. Recently, $1T$ -TaS₂ has attracted more attention because of the theoretical prediction and experimental exploration of the possible quantum spin liquid state [13–18].

In general, the band filling n , the on-site Coulomb energy U , and the one-electron bandwidth W together drive the Mott insulator transition in a coordinated manner [19]. Unlike other conventional Mott insulators, the on-site Coulomb energy U in $1T$ -TaS₂ is not large enough to directly open a Mott gap. The essential ingredient here is that the presence of the commensurate CDW with a David star structure isolates a narrow energy band near the Fermi energy [20]. This band mainly consists of the $5d$ orbitals at the center of the David star [21]. Therefore, a moderate U can open a Mott gap in this narrow band which is half filled.

The metallization of $1T$ -TaS₂ is believed to be accompanied with the breaking of the long-range CDW order; i.e., the metallic phase starts to initiate at the domain boundaries of the CDW state [22], where the long-range order is simultaneously destructed. The metallization has been

realized experimentally via applying pressure [11], chemical substitution [23], ultrafast laser pulses [24], current excitation [25,26] or applying a pulse voltage [27], which induce domain boundaries and suppress the long-range CDW order [11,23–27]. However, the nature of Mott insulator-metal transition in $1T$ -TaS₂ still remains elusive, partially owing to the complex correlation between the Mott insulator and the CDW state. It is not even clear whether the collapse of the Mott gap is necessarily connected with the destruction of the long-range CDW order.

In this work, we explore the Mott insulator-metal transition of $1T$ -TaS₂ upon surface doping by alkali K atoms. The K atoms deposited onto the surface will transfer electrons to the host lattice to increase the band filling [28], and the left K⁺ ions effectively modify the crucial parameters U/W of the Mott insulator-metal transition. In the meantime, such a method induces a negligible orbital effect, which may complicate the related physics [29]. By using scanning tunneling microscopy or spectroscopy (STM/STS), we directly characterize the electronic state evolution from Mott insulator to metal. Surprisingly, we find the long range CDW order is always persisting during the metallization, indicating that such Mott insulator-metal transition is fundamentally different from that triggered by the domain boundaries of the CDW [23,30–32]. The metallization is found to arise from the filling up of the Mott gap by additional in-gap excitations induced by the surface alkali doping. Though this phenomenon is common for conventional Mott insulators, such as the doped high- T_c cuprates [33], we observe that the in-gap

excitation is unexpectedly located above the lower Hubbard band (LHB), which is underneath the upper Hubbard band (UHB) in the case of electron doped conventional Mott insulators. Considering that the Mott insulating state in 1T-TaS₂ is derived from the isolated narrow band due to the CDW, we construct a single-band Hubbard model with a site-dependent U to account for the possible effect of the surface K⁺ ions. Using the cluster perturbation theory (CPT), we calculate the spectral function of electrons and find qualitative consistency with experiments. We therefore suggest that the K⁺ ions adsorbed at the center of the David star would effectively reduce the Coulomb energy U and result in the appearance of the in-gap excitations near the LHB.

The 1T-TaS₂ single crystal was grown by the chemical vapor transport method. STM and STS measurements were carried out in a low-temperature scanning tunneling microscope (Unisoku Co.) at ~ 4.2 K in ultrahigh vacuum (UHV), with the base pressure of 1×10^{-10} mbar. The clean surface of 1T-TaS₂ was achieved by cleaving the sample *in situ* in UHV. The sample was kept at ~ 4.2 K and then quickly transferred to the evaporation chamber prior to K deposition. The K source (SAES, Alkali metal dispenser) was heated to ~ 650 °C, and the atomic flux of K is estimated to be ~ 0.005 ML/s. After the deposition, the sample was transferred to the STM stage for a scan without annealing. Because of the strong enough bonding to the 1T-TaS₂ surface, the K atoms are static during a normal scan. STM topographic images were collected under the constant current mode. STS dI/dV spectra were taken with a lock-in amplifier and a typical ac modulation of 10 mV and 879 Hz.

The bulk 1T-TaS₂ crystal has a layered structure [34]. The Ta atomic layer is sandwiched between two S atomic layers. In the normal state, the Ta atoms sit at the center of the approximate S octahedra. In the CDW phase, 1T-TaS₂ forms a $\sqrt{13} \times \sqrt{13}$ superstructure composed of the David star clusters, as shown in Fig. 1(a). A high-resolution STM image taken in this CDW phase is displayed in Fig. 1(b). Close examination reveals the position of the topmost S atoms in each David star cluster. There exist three inequivalent types of Ta atoms in the unit cell designated by different colors in Figs. 1(b) and 1(c).

The dI/dV spectrum, which is proportional to the electron local density of states (LDOS), is taken on the 1T-TaS₂ surface and plotted in Fig. 1(d). The UHB and LHB can be clearly identified as the peaks marked in the dI/dV curve, in agreement with the previous reports [35]. These spectroscopic features can be captured by DFT calculations including the on-site Hubbard U correction in a Hartree-Fock approximation [36]. The peak below the LHB is referred to as the valence band (VB). The CDW gap thus locates between the LHB and the VB [37–39]. The conduction band (CB) is located above the UHB.

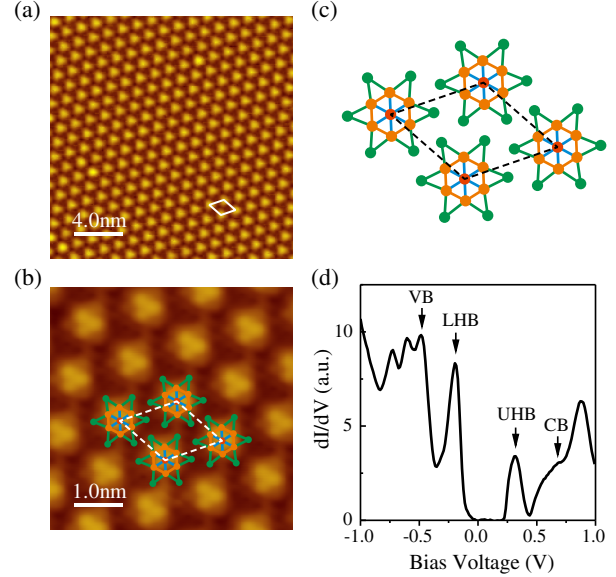


FIG. 1. (a) STM topographic image (40×40 nm²) taken at ~ 4.2 K on the pristine 1T-TaS₂ surface, showing the $\sqrt{13} \times \sqrt{13}$ periodicity. $U = +1.0$ V and $I_t = 100$ pA. (b) High-resolution STM image (5×5 nm²) showing the atomic structure of the David star. The David star model is overlaid on the STM image. $U = +100$ mV and $I_t = 200$ pA. Individual S atoms are resolved as small blobs in each David star cluster, which enables us to identify the position of Ta atoms underneath. (c) Schematic of the top view David star structure. Different colors represent the inequivalent Ta atoms derived from different positions in the David star cluster. (d) Spatially averaged dI/dV spectrum acquired with $U = +500$ mV and $I_t = 100$ pA.

The evolution of dI/dV spectra upon K doping to the 1T-TaS₂ surface is plotted in Fig. 2(a). Initially, the Fermi level starts to lift slightly towards the UHB. Yet, the whole characteristics of the spectra do not seem to change, as exemplified by the plot of 0.05 ML in Fig. 2(a). This can be interpreted as that the K electrons are trapped by the surface impurities for a small amount of K deposition. When more K atoms are deposited, e.g., from 0.08 ML on in Fig. 2(a), additional excitations become identifiable within the Mott gap, indicating that the K electrons dope the Mott insulator effectively. An important feature is that these additional excitations are close to the LHB. They keep growing until the whole Mott gap is filled up when the coverage reaches ~ 0.32 ML. At this coverage, the collected dI/dV results exhibit the uniform metallic state on the whole 1T-TaS₂ surface, and thus the surface undergoes a transition from Mott insulator to metal. To quantitatively analyze the electronic evolution, we define the CDW gap Δ_{CDW} as the width from the VB peak to the LHB peak, Δ_{Mott} from the LHB peak to the UHB peak, and Δ_0 for the zero intensity region accordingly, as illustrated in Fig. 2(b). Figure 2(c) shows the magnitude of the three gaps as a function of the K coverage. At first, Δ_0 is closed at ~ 0.32 ML. Second, during the Mott insulator-metal

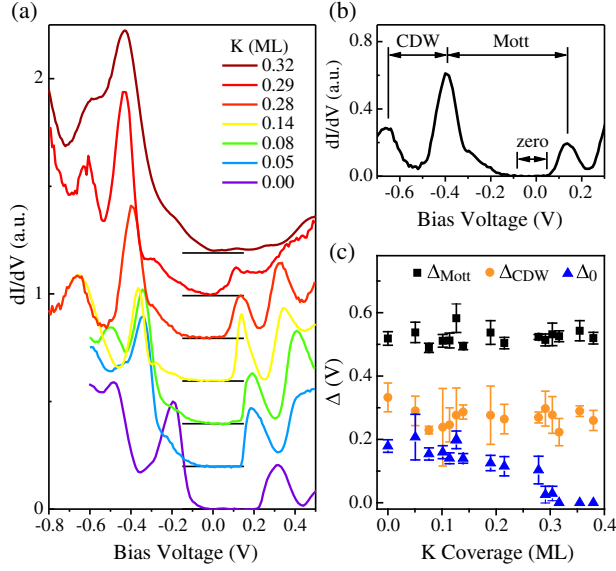


FIG. 2. (a) dI/dV spectra taken on the $1T$ -TaS₂ surface with different K coverage. The data were acquired with $U = +500$ mV and $I_t = 100$ pA. (b) Definition of the three gaps in the $1T$ -TaS₂ dI/dV spectrum. Δ_{Mott} is defined as the width between the two Hubbard peaks, Δ_{CDW} the width between LHB and VB peaks, and Δ_0 the width of the zero-intensity region within the Mott gap. (c) Dependence of the magnitude of the three gaps on the K coverage.

transition, the UHB and LHB peaks are both identifiable, and the magnitude of Δ_{Mott} does not prominently change. Third, no change is observed in the magnitude of Δ_{CDW} . The peak of VB remains at a fixed position relative to the LHB as the K coverage increases. Therefore, the electron doping by K atoms on the surface of $1T$ -TaS₂ does not close the CDW gap in the process of the metallization.

I We further explore the effects of the alkali doping on the long-range CDW order. Figure 3(a) shows the STM topographic image of the $1T$ -TaS₂ surface with a low coverage of K atoms. The identified David star clusters form a triangular structure as traced by the yellow dashed mesh where each cluster is denoted by the crossing. The K atom is adsorbed preferentially on top of the center of the David star cluster. Then, we present the image of the surface covered with a high coverage of ~ 0.4 ML in Fig. 3(b), where all the K atoms are still in a single-atom format without clustering. Figure 3(c) shows the zoom-in image of the white square region in Fig. 3(b), where the black mesh and dots represent the David star structure and adsorbed K atoms, respectively. We find that 152 of the total 162 K atoms are located at the David star center. This analysis suggests that the long-range CDW order still remains at this coverage. Moreover, Fig. 3(d), the Fourier transform of Fig. 3(b), shows that the peak corresponding to the CDW periodicity as marked by the blue circle is rather sharp, indicating the long-range CDW order without domain boundary. It is a remarkable result because the whole

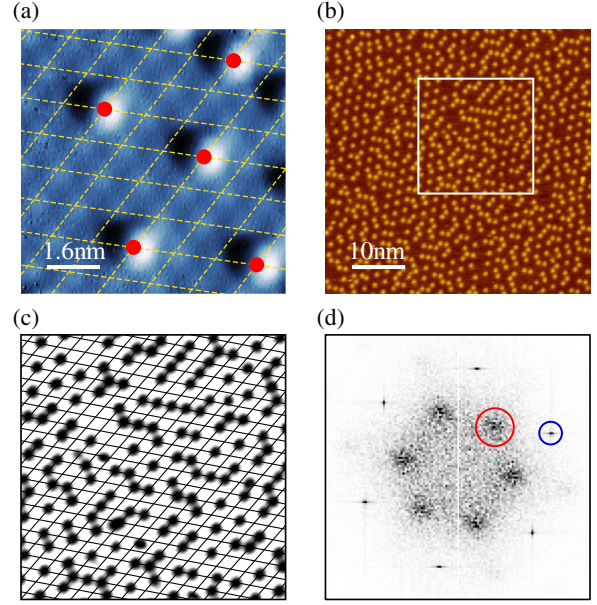


FIG. 3. (a) Small-scale STM current image (8×8 nm²) taken at the $1T$ -TaS₂ surface with a low K coverage. The David star structure is highlighted by the yellow dashed mesh, and the adsorption sites of K at the David star center are marked by red dots. (b) Large-scale STM topographic image (50×50 nm²) taken on the $1T$ -TaS₂ surface with the K coverage of ~ 0.4 ML. $U = +1.0$ V and $I_t = 100$ pA. (c) The adsorption sites of K atoms extracted from the white square region in (b). The black dots represent the positions of K atoms, and the parallel lines the lattice of the $1T$ -TaS₂ substrate. (d) Fourier transform of the STM image (b). The blue and red circles mark the peaks originated from the surface K atoms.

$1T$ -TaS₂ surface is already metallic at this coverage. In previous studies of the Mott insulator-metal transition in $1T$ -TaS₂, such as that induced by applying pressure [11], chemical substitution [23], ultrafast laser pulses [24], current excitation [25,26] or applying a pulse voltage [27], the domain boundaries were found to be responsible to the formation of the metallic state. However, in the K doped $1T$ -TaS₂ surface, the formation of the domain boundary is not necessary for the metallization, and this Mott insulator-metal transition occurs without the destruction of the long-range CDW order.

With the presence of the long-range CDW order in mind, we expect that a single-band Hubbard model would capture the main physics of the Mott insulator-metal transition, as the isolated narrow band still exists. Figure 4(a) schematically illustrates the spectral weight transfer in the conventional Hubbard model with electron doping [40,41]. In the large U ($U/t \rightarrow \infty$) limit and with half filling, the spectral weight integrals of the LHB and UHB divided by the number of lattice sites are both equal to 1. When extra electrons are introduced into this system, both the possibilities of creating holes (removing electrons from the LHB) and double occupancies (adding electrons into the

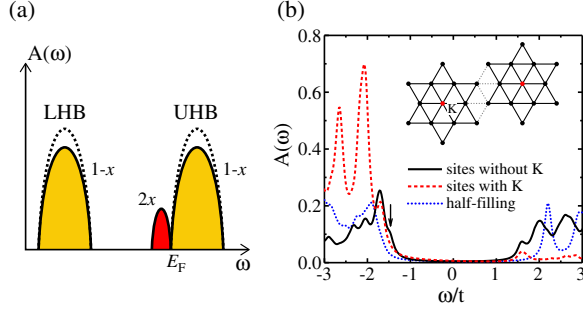


FIG. 4. (a) Schematic of the spectral weight transfer in the local limit for an electron-doped Hubbard model with a uniform U . (b) Spectra calculated by the cluster perturbation theory. The spectrum of the half-filled system is illustrated by the dotted (blue) line, while the spectra in the sites with and without K^+ ions which are simulated by different U (see the text) after one-electron doping in the 13-site cluster are illustrated by the dashed (red) line and solid (black) line, respectively. The arrow indicates the in-gap excitation near the LHB. The inset shows the shape of clusters used in the theoretical calculations.

UHB) are reduced by the doping concentration x . Thus, the total spectral weight of LHB and UHB are changed to $1 - x$, and the reduced spectral weight shifts to the bottom of the UHB, which is just below the Fermi level, as illustrated in Fig. 4(a). However, this picture clearly contradicts the experimental results as shown in Fig. 2, because the additional excitation is observed near the top of LHB and the spectral intensity of LHB is increased.

As mentioned above, the experimental results show that each K^+ ion is located at the center of one David star, so the electron concentration for the David stars with K^+ ions is larger than those without K^+ ions due to the Coulomb attraction of the positive charge of K^+ , which is equivalent to the decrease of the effective repulsive interactions between electrons in the lattice sites with K^+ ions. Thus, we construct a site-dependent Hubbard model as described by

$$H = \sum_{\langle i,j \rangle \sigma} t_{ij} (c_{i\sigma}^\dagger c_{j\sigma} + \text{H.c.}) + \sum_i U_i n_{i\uparrow} n_{i\downarrow}, \quad (1)$$

where t_{ij} is the effective hopping between the nearest-neighbor David stars and U_i the effective on-site Coulomb repulsion. In theoretical calculations, we set t_{ij} to be uniform $t_{ij} = t$, and $U_i = 10t$ for David stars without K^+ deposition and $U_i = 2t$ for David stars with K^+ deposition. We calculate the LDOS by using the cluster perturbation theory [41–43]. As shown in the inset of Fig. 4(b), to preserve the rotation symmetry of the triangular lattice, we use 13-site clusters and set the K^+ ion at the center of each cluster. It is noteworthy that each site in the model represents a David star in the real material. The theoretical results of LDOS at half filling and with one electron doping in the 13-site clusters are shown in

Fig. 4(b). For the half-filling system, a Mott gap of about $4t$ is clearly seen, while for the doped system, there exist additional excitations inside the Mott gap and close to the LHB for the David stars without K^+ deposition. This feature is qualitatively consistent with the experimental observation. We also present the LDOS for the David stars with K^+ deposition in Fig. 4(b). Since the effective interaction U becomes small, most spectral weights are transferred to the low-energy part. The coupling between the David stars with and without K^+ deposition causes the redistribution of the spectral weight on the David stars without K^+ deposition, which leads to the appearance of the in-gap excitations near the LHB as observed in experiment.

In summary, we realize a novel Mott insulator-metal transition in the surface of the CDW-assisted Mott insulator 1T-TaS₂ by surface alkali doping. Different from those triggered by the domain boundaries of the CDW state in which the long-range order of the CDW is destructed, we find that the long-range CDW order here is preserved all the way in the metallization, and the transition results from the filling up of the Mott gap by the in-gap additional excitations induced by the surface alkali doping. Moreover, the in-gap additional excitations are found to locate above the LHB, in contrast to the case of electron doped conventional Mott insulators where it is underneath the UHB. Making use of the numerical calculations of the site-dependent Hubbard model, we suggest that it is the K^+ ions adsorbed at the center of David stars that efficiently modulate the Coulomb energy and thus result in the appearance of the in-gap excitations near the LHB. This study paves the way toward the understanding of the correlation between a CDW and Mott insulators in transition metal dichalcogenides.

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X. Y. Z. and S. W. contributed equally to this work.

Note added.—This work is premised on the assumption that the insulating state in 1T-TaS₂ is due to Mott gap opening in the narrow band crossing the Fermi level, and the assumption that the physics is essentially 2D. There are other proposals that the metal-insulator transition is related to stacking order changes because of the strong interlayer coupling [49].

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